Diode Semiconductor Device - Page 1 of 1



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## Inclosure Material:

Metal

### Overall Length:

Between 5.015 inches and 5.685 inches

# Mounting Facility Quantity:

1

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### Do-30

#### **Mounting Method:**

Threaded stud

#### **Features Provided:**

Reverse polarity

### **Overall Width Across Flats:**

Between 1.031 inches and 1.063 inches

#### **Thread Size:**

0.500 inches

### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

300.0 repetitive peak reverse voltage and 240.0 reverse voltage, instantaneous

# **Current Rating Per Characteristic:**

17.00 milliamperes forward current, average minor

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Thread Series Designator:**

Unf

## **Terminal Type And Quantity:**

1 threaded stud and 1 unthreaded hole

Shelf Life:

N/a

#### Unit Of Measure:

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# Demilitarization:

No

#### Fiig:

A110a0